

NE558

LINEAR INTEGRATED CIRCUIT

QUAD TIMER

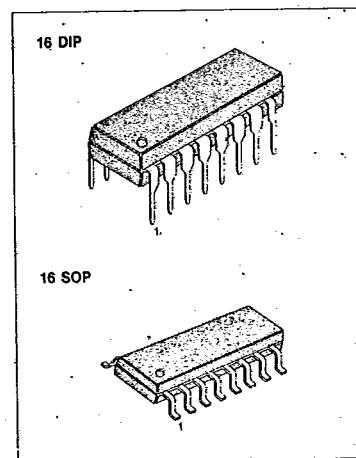
The NE558 series are a monolithic Quad Timers which can be used to produce four entirely independent timing functions. These highly stable, general purpose controllers can be used in a monostable mode to produce accurate time delays, from microseconds to hours. The time is precisely controlled by one external resistor and one capacitor in the time delay mode. A stable mode can be operated by using two of four timer sections.

FEATURES

- Wide supply voltage range: 4.5V to 16V
- 100mA output current per section
- Edge triggered without coupling capacitor
- Time period equals RC
- Output independent of trigger conditions.

APPLICATIONS

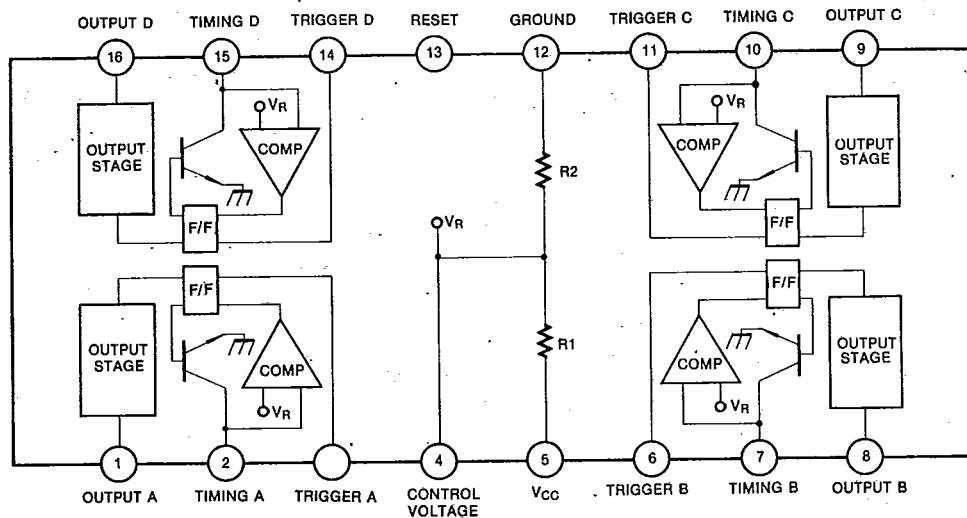
- Quad one-shot
- Sequential timing
- Precision timing
- Time delay generation



ORDERING INFORMATION

Device	Package	Operating Temperature
NE558IN	14 DIP	-45 ~ +85°C
NE558CN	14 DIP	0 ~ +70°C
NE558CD	14 SOP	

BLOCK DIAGRAM



SAMSUNG SEMICONDUCTOR

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ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Value	Unit
Supply Voltage	V_{CC}	18	V
Lead Temperature (soldering 10 sec)	T_{lead}	300	$^\circ\text{C}$
Power Dissipation	P_D	600	mW
Operating Temperature NE556I NE556C	T_{opr}	-40 ~ +85	$^\circ\text{C}$
Storage Temperature	T_{stg}	0 ~ 70	$^\circ\text{C}$
		-65 ~ +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = 5\text{V} \sim 15\text{V}, T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Voltage	V_{CC}		4.5		16	V
Supply Current	I_{CC}	$V_{CC} = 15\text{V}$, reset voltage = 15V		16	36	mA
Timing Error ($T = RC$)				± 2	5	%
Initial Accuracy				30	150	PPM/ $^\circ\text{C}$
Drift with Temperature		$R = 2\text{K}\Omega$ to $100\text{K}\Omega$, $C = 1\mu\text{F}$		0.1	0.9	%/V
Drift with Supply Voltage						
Trigger Voltage	V_{TR}	$V_{CC} = 15\text{V}$	0.8	1.5	2.4	V
Trigger Current	I_{TR}	Trigger voltage = 0V		50	100	μA
Reset Voltage	V_{RE}	Reset	0.8		2.4	V
Reset Current	I_{RE}	Reset		50	500	μA
Threshold Voltage	V_{TH}			0.63 $\times V_{CC}$		V
Threshold Current	I_{TL}			15		nA
Output Voltage	V_{OUT}	$I_L = 10\text{mA}$		0.1	0.4	V
		$I_L = 100\text{mA}$		1.0	2.0	
Output Leakage Current	I_{OL}			10	500	nA
Propagation Delay Time	T_P			1.0		μs
Rise Time	T_r	$I_L = 100\text{mA}$		100		nS
Fall Time	T_f	$I_L = 100\text{mA}$		100		nS

- NOTES:
1. The trigger functions only on the falling edge of the trigger pulse only after previously being high. After reset the trigger must be brought high and then low to implement triggering.
 2. For reset below 0.8V, outputs set low and trigger inhibited.
 3. Output structure is open collector which requires a pull up resistor to V_{CC} to sink current.
The output is normally low sinking current.



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APPLICATIONS

- Long-Time Delay

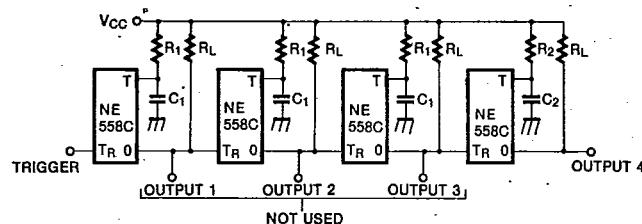
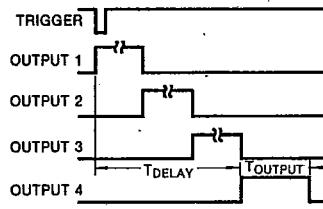


Fig. 1. Circuit

 $T_{DELAY} = 3(R_1 C_1)$ $T_{OUT} = R_2 C_2$

- Ring Counter

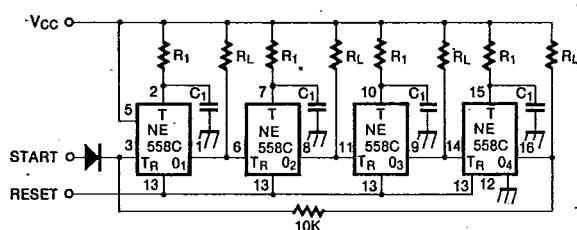


Fig. 3. Circuit

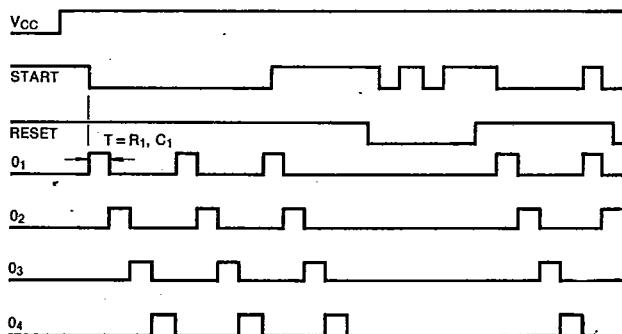


Fig. 4. Timing Chart



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